DRV8872 3.6-A Brushed DC Motor Driver With Fault Reporting (PWM Control)

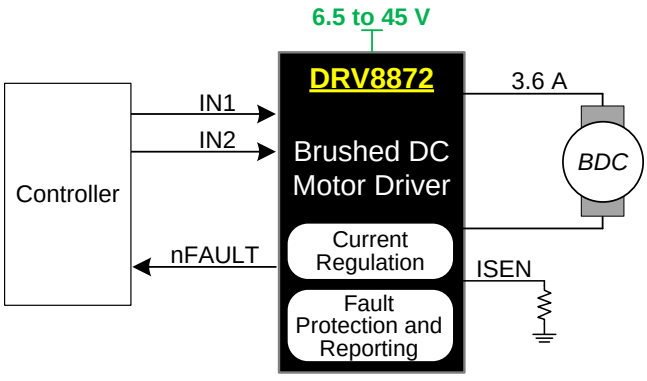
1 Features

- H-Bridge Motor Driver
  - Drives One DC Motor, One Winding of a Stepper Motor, or Other Loads
- Wide 6.5-V to 45-V Operating Voltage
- 565-mΩ Typical $R_{DS(on)}$ (HS + LS)
- 3.6-A Peak Current Drive
- PWM Control Interface
- Integrated Current Regulation
- Low-Power Sleep Mode
- Fault Status Output Pin
- Small Package and Footprint
  - 8-Pin HSOP With PowerPAD™
  - 4.9 × 6 mm
- **Integrated Protection Features**
  - VM Undervoltage Lockout (UVLO)
  - Overcurrent Protection (OCP)
  - Thermal Shutdown (TSD)
  - Fault Reporting (nFAULT)
  - Automatic Fault Recovery

2 Applications

- Printers
- Appliances
- Industrial Equipment
- Other Mechatronic Applications

Simplified Schematic



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3 Description

The DRV8872 device is a brushed-DC motor driver for printers, appliances, industrial equipment, and other small machines. Two logic inputs control the H-bridge driver, which consists of four N-channel MOSFETs that can control motors bidirectionally with up to 3.6-A peak current. The inputs can be pulse-width modulated (PWM) to control motor speed, using a choice of current-decay modes. Setting both inputs low enters a low-power sleep mode.

The DRV8872 device features integrated current regulation, based on an internal reference voltage and the voltage on pin ISEN, which is proportional to motor current through an external sense resistor. The ability to limit current to a known level can significantly reduce the system power requirements and bulk capacitance needed to maintain stable voltage, especially for motor startup and stall conditions.

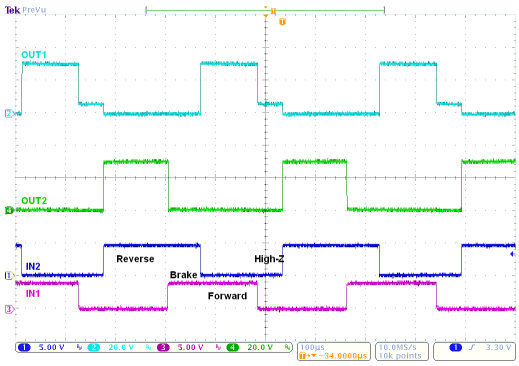
The device is fully protected from faults and short circuits, including undervoltage (UVLO), overcurrent (OCP), and overtemperature (TSD). Faults are communicated by pulling the nFAULT output low. When the fault condition is removed, the device automatically resumes normal operation.

Device Information (1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
DRV8872	HSOP (8)	4.90 mm × 6.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

H-Bridge States



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (January 2016) to Revision C — **Page**

- Deleted the power supply voltage ramp rate (VM) parameter from the *Absolute Maximum Ratings* table ... 3
- Added the output current parameter to the *Absolute Maximum Ratings* table ... 3
- Added the *Receiving Notification of Documentation Updates* section ... 17

Changes from Revision A (August 2015) to Revision B — **Page**

- Updated the f_{PWM} max value and added a note ... 4
- Removed the redundant T_A condition and added f_{PWM} = 24 kHz ... 5
- Added more information to clarify how the max RMS current varies for different applications ... 12

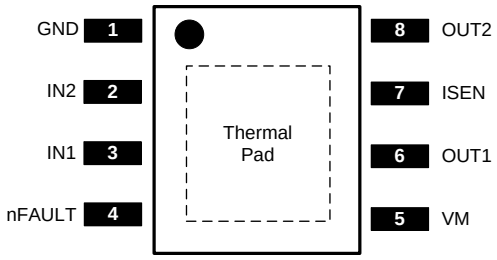
Changes from Original (August 2015) to Revision A — **Page**

- Updated conditions for Figure 12 ... 13

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5 Pin Configuration and Functions

DDA Package
8-Pin HSOP With Exposed Thermal Pad
Top View



Pin Functions

PIN		TYPE	DESCRIPTION	
NAME	NO.			
GND	1	PWR	Logic ground	Connect to board ground.
IN1	3	I	Logic inputs	Controls the H-bridge output. Has internal pulldowns. (See Table 1.)
IN2	2			
ISEN	7	PWR	High-current ground path	If using current regulation, connect ISEN to a resistor (low-value, high-power-rating) to ground. If not using current regulation, connect ISEN directly to ground.
nFAULT	4	OD	Fault status (open-drain)	Low-level indicates UVLO, TSD, or OCP fault. Connect to a pullup resistor.
OUT1	6	O	H-bridge outputs	Connect directly to the motor, or other inductive load.
OUT2	8			
VM	5	PWR	6.5-V to 45-V power supply	Connect a 0.1-µF bypass capacitor to ground, as well as sufficient bulk capacitance, rated for the VM voltage.
PAD	—	—	Thermal pad	Connect to board ground. For good thermal dissipation, use large ground planes on multiple layers, and multiple nearby vias connecting those planes.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
Power supply voltage (VM)	–0.3	50	V
Logic input voltage (IN1, IN2)	–0.3	7	V
Fault pin (nFAULT)	–0.3	6	V
Continuous phase node pin voltage (OUT1, OUT2)	–0.7	VM + 0.7	V
Current sense input pin voltage (ISEN)(2)	–0.5	1	V
Output current (100% duty cycle)	0	3.5	A
Operating junction temperature, T_J	–40	150	°C
Storage temperature, T_{stg}	–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Transients of ±1 V for less than 25 ns are acceptable

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6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±6000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±750	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
VM	Power supply voltage	6.5		45	V
V_I	Logic input voltage (IN1, IN2)	0		5.5	V
f_{PWM}	Logic input PWM frequency (IN1, IN2)	0		200 (1)	kHz
I_{peak}	Peak output current (2)	0		3.6	A
T_A	Operating ambient temperature	–40		125	°C

(1) The voltages applied to the inputs should have at least 800 ns of pulse width to ensure detection. Typical devices require at least 400 ns. If the PWM frequency is 200 kHz, the usable duty cycle range is 16% to 84%
(2) Power dissipation and thermal limits must be observed

6.4 Thermal Information

THERMAL METRIC (1)		DRV8872 DDA (HSOP) 8 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	41.1	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	53.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	23.1	°C/W
ψ_{JT}	Junction-to-top characterization parameter	8.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	23	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	2.7	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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6.5 Electrical Characteristics

T_A = 25°C, over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY (VM)						
VM	VM operating voltage		6.5		45	V
I_{VM}	VM operating supply current	VM = 12 V		3	10	mA
$I_{VMSLEEP}$	VM sleep current	VM = 12 V			10	µA
t_{ON}	Turn-on time(1)	VM > V_{UVLO} with IN1 or IN2 high		40	50	µs
LOGIC-LEVEL INPUTS (IN1, IN2)						
V_{IL}	Input logic low voltage				0.5	V
V_{IH}	Input logic high voltage		1.5			V
V_{HYS}	Input logic hysteresis			0.5		V
I_{IL}	Input logic low current	V_{IN} = 0 V	–1		1	µA
I_{IH}	Input logic high current	V_{IN} = 3.3 V		33	100	µA
R_{PD}	Pulldown resistance	To GND		100		kΩ
t_{PD}	Propagation delay	INx to OUTx change (see Figure 6)		0.7	1	µs
t_{sleep}	Time to sleep	Inputs low to sleep		1	1.5	ms
MOTOR DRIVER OUTPUTS (OUT1, OUT2)						
$R_{DS(ON)}$	High-side FET on resistance	VM = 24 V, I = 1 A, f_{PWM} = 25 kHz		307	360	mΩ
$R_{DS(ON)}$	Low-side FET on resistance	VM = 24 V, I = 1 A, f_{PWM} = 25 kHz		258	320	mΩ
t_{DEAD}	Output dead time			220		ns
V_d	Body diode forward voltage	I_{OUT} = 1 A		0.8	1	V
CURRENT REGULATION						
V_{TRIP}	ISEN voltage for current chopping		0.32	0.35	0.38	V
t_{OFF}	PWM off-time			25		µs
t_{BLANK}	PWM blanking time			2		µs
PROTECTION CIRCUITS						
V_{UVLO}	VM undervoltage lockout	VM falls until UVLO triggers		6.1	6.4	V
		VM rises until operation recovers		6.3	6.5	
$V_{UV,HYS}$	VM undervoltage hysteresis	Rising to falling threshold	100	180		mV
I_{OCP}	Overcurrent protection trip level		3.7	4.5	6.4	A
t_{OCP}	Overcurrent deglitch time			1.5		µs
t_{RETRY}	Overcurrent retry time			3		ms
T_{SD}	Thermal shutdown temperature		150	175		°C
T_{HYS}	Thermal shutdown hysteresis			40		°C
nFAULT OPEN DRAIN OUTPUT						
V_{OL}	Output low voltage	I_O = 5 mA			0.5	V
I_{OH}	Output high leakage current	V_O = 3.3 V			1	µA

(1) t_{ON} applies when the device initially powers up, and when it exits sleep mode.

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6.6 Typical Characteristics

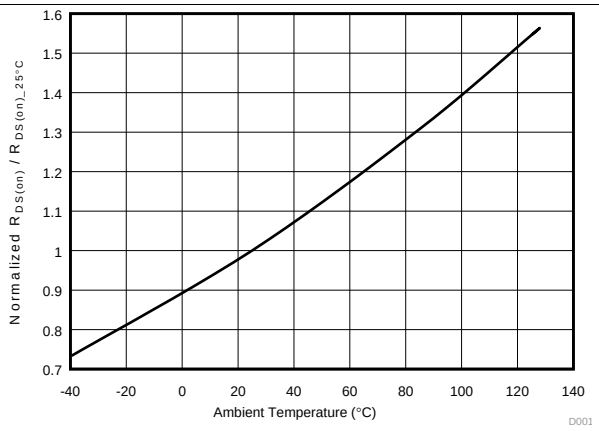


Figure 1. $R_{DS(on)}$ vs Temperature

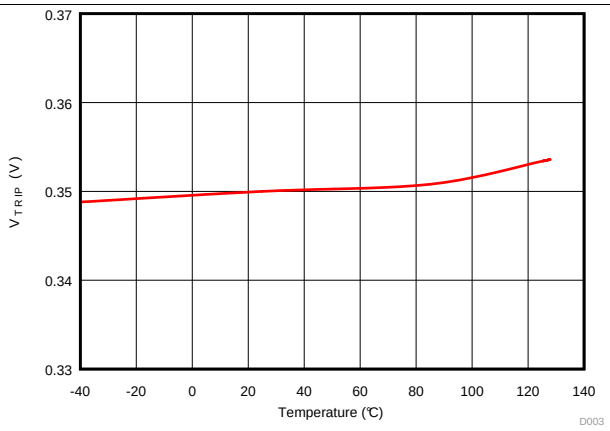


Figure 2. V_{TRIP} vs Temperature

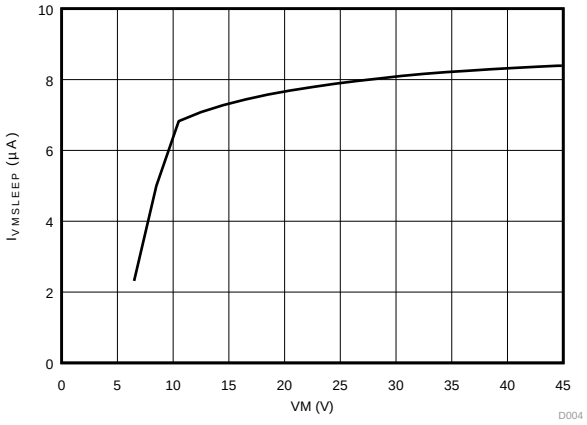


Figure 3. $I_{VMSLEEP}$ vs VM at 25°C

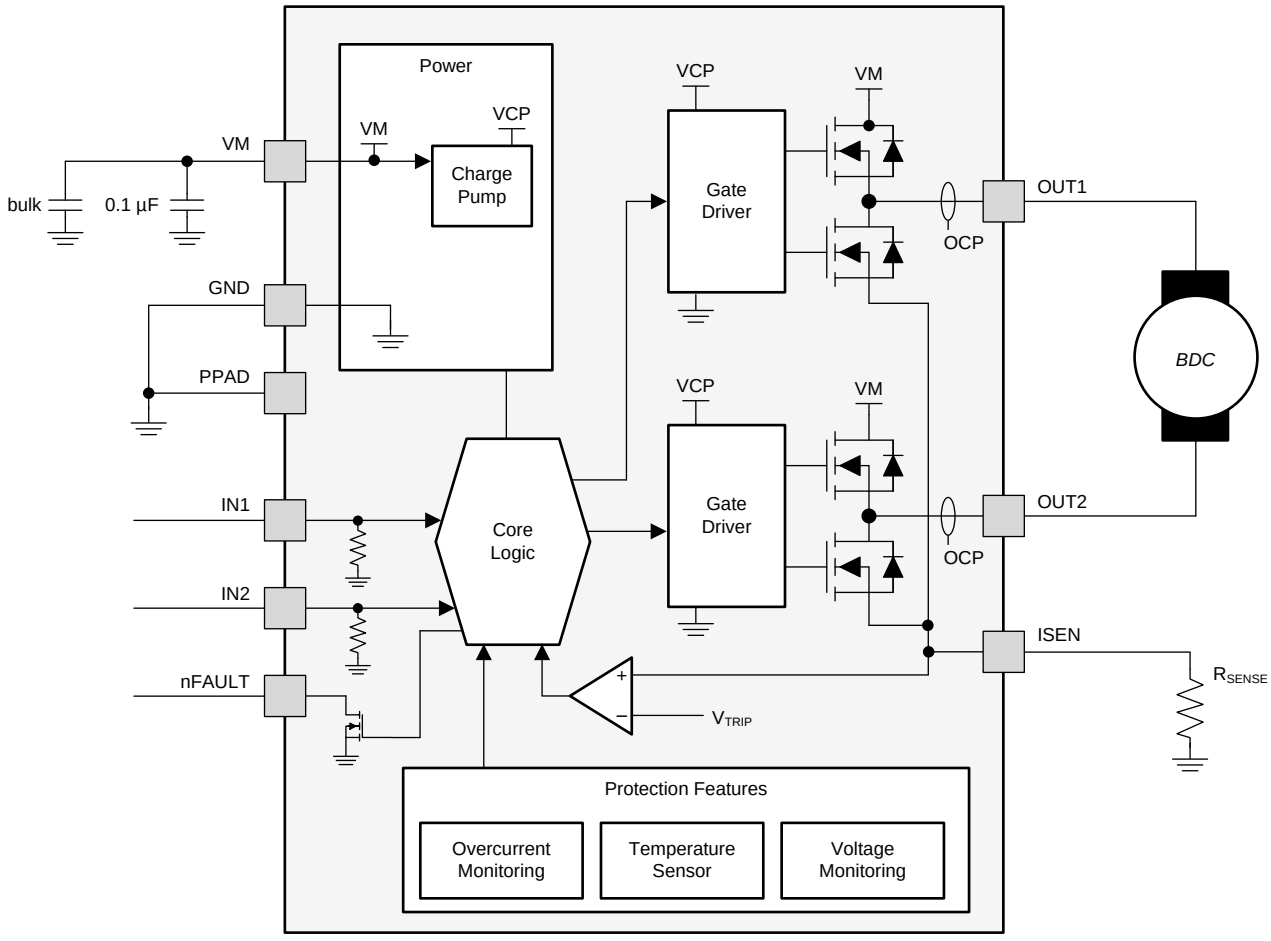
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7 Detailed Description

7.1 Overview

The DRV8872 device is an optimized 8-pin device for driving brushed DC motors with 6.5 to 45 V and up to 3.6-A peak current. The integrated current regulation restricts motor current to a predefined maximum. Two logic inputs control the H-bridge driver, which consists of four N-channel MOSFETs that have a typical $R_{ds(on)}$ of 565 mΩ (including one high-side and one low-side FET). A single power input, VM, serves as both device power and the motor winding bias voltage. The integrated charge pump of the device boosts VM internally and fully enhances the high-side FETs. Motor speed can be controlled with pulse-width modulation, at frequencies between 0 to 100 kHz. The device has an integrated sleep mode that is entered by bringing both inputs low. An assortment of protection features prevent the device from being damaged if a system fault occurs.

7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 Bridge Control

The DRV8872 output consists of four N-channel MOSFETs that are designed to drive high current. These MOSFETs are controlled by the two logic inputs IN1 and IN2, according to Table 1.

Table 1. H-Bridge Control

IN1	IN2	OUT1	OUT2	DESCRIPTION
0	0	High-Z	High-Z	Coast; H-bridge disabled to High-Z (sleep entered after 1 ms)
0	1	L	H	Reverse (current OUT2 → OUT1)
1	0	H	L	Forward (current OUT1 → OUT2)
1	1	L	L	Brake; low-side slow decay

The inputs can be set to static voltages for 100% duty-cycle drive, or they can be pulse-width modulated (PWM) for variable motor speed. When using PWM, switching between driving and braking typically works best. For example, to drive a motor forward with 50% of its max RPM, IN1 = 1 and IN2 = 0 during the driving period, and IN1 = 1 and IN2 = 1 during the other period. Alternatively, the coast mode (IN1 = 0, IN2 = 0) for *fast current decay* is also available. The input pins can be powered before VM is applied.

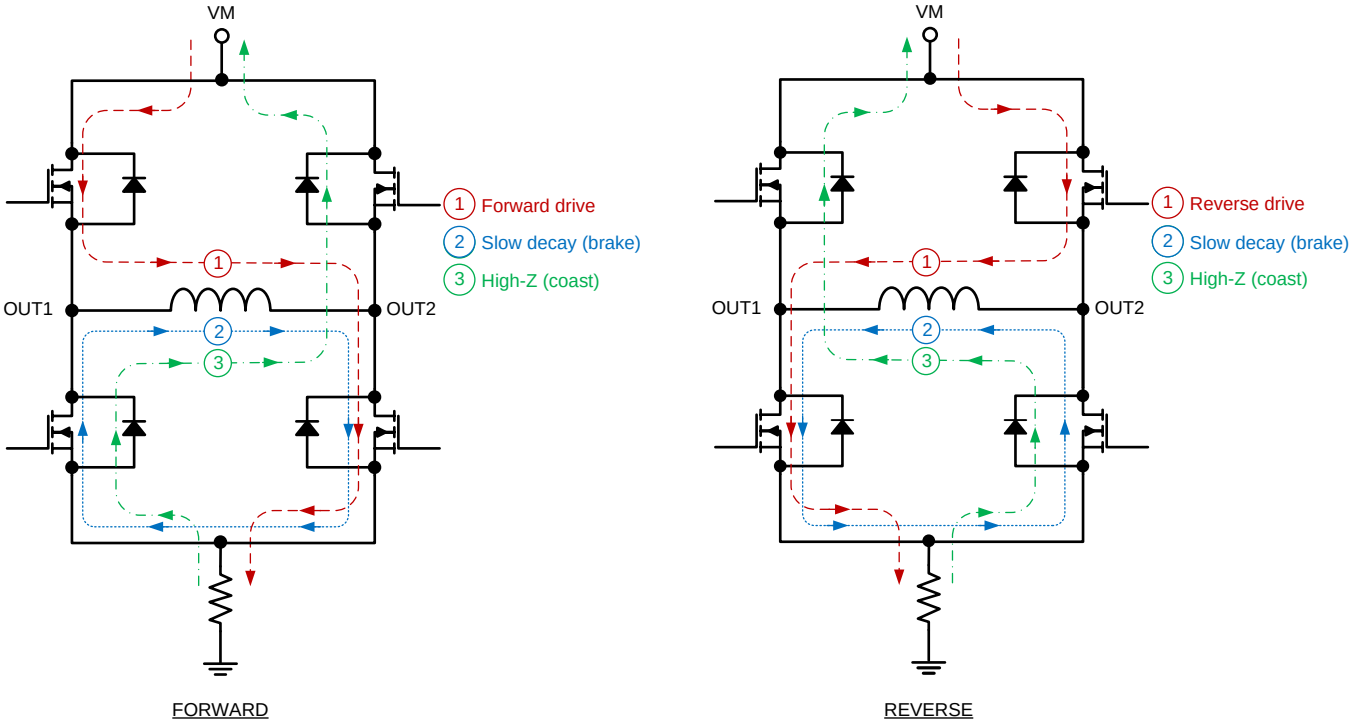


Figure 4. H-Bridge Current Paths

7.3.2 Sleep Mode

When IN1 and IN2 are both low for time t_{SLEEP} (typically 1 ms), the DRV8872 device enters a low-power sleep mode, where the outputs remain High-Z and the device uses $I_{VMSLEEP}$ (microamps) of current. If the device is powered up while both inputs are low, sleep mode is immediately entered. After IN1 or IN2 are high for at least 5 µs, the device is operational 50 µs (t_{ON}) later.

7.3.3 Current Regulation

The DRV8872 device limits the output current based on the resistance of an external sense resistor on pin ISEN, according to Equation 1.

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$$I_{TRIP}\ (A) = \frac{V_{TRIP}\ (V)}{R_{ISEN}\ (\Omega)} = \frac{0.35\ (V)}{R_{ISEN}\ (\Omega)} \quad (1)$$

For example, if R_{ISEN} = 0.16 Ω, the DRV8872 device limits motor current to 2.2 A no matter how much load torque is applied. For guidelines on selecting a sense resistor, see the *Sense Resistor* section.

When I_{TRIP} has been reached, the device enforces slow current decay by enabling both low-side FETs, and it does this for time t_{OFF} (typically 25 µs).

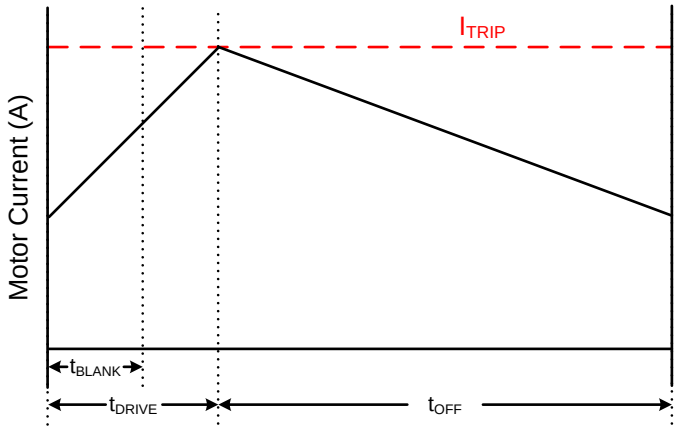


Figure 5. Current Regulation Time Periods

After t_{OFF} has elapsed, the output is re-enabled according to the two inputs INx. The drive time (t_{DRIVE}) until reaching another I_{TRIP} event heavily depends on the VM voltage, the back-EMF of the motor, and the inductance of the motor.

7.3.4 Dead Time

When an output changes from driving high to driving low, or driving low to driving high, dead time is automatically inserted to prevent shoot-through. t_{DEAD} is the time in the middle when the output is High-Z. If the output pin is measured during t_{DEAD}, the voltage will depend on the direction of current. If current is leaving the pin, the voltage is a diode drop below ground. If current is entering the pin, the voltage is a diode drop above VM. This diode is the body diode of the high-side or low-side FET.

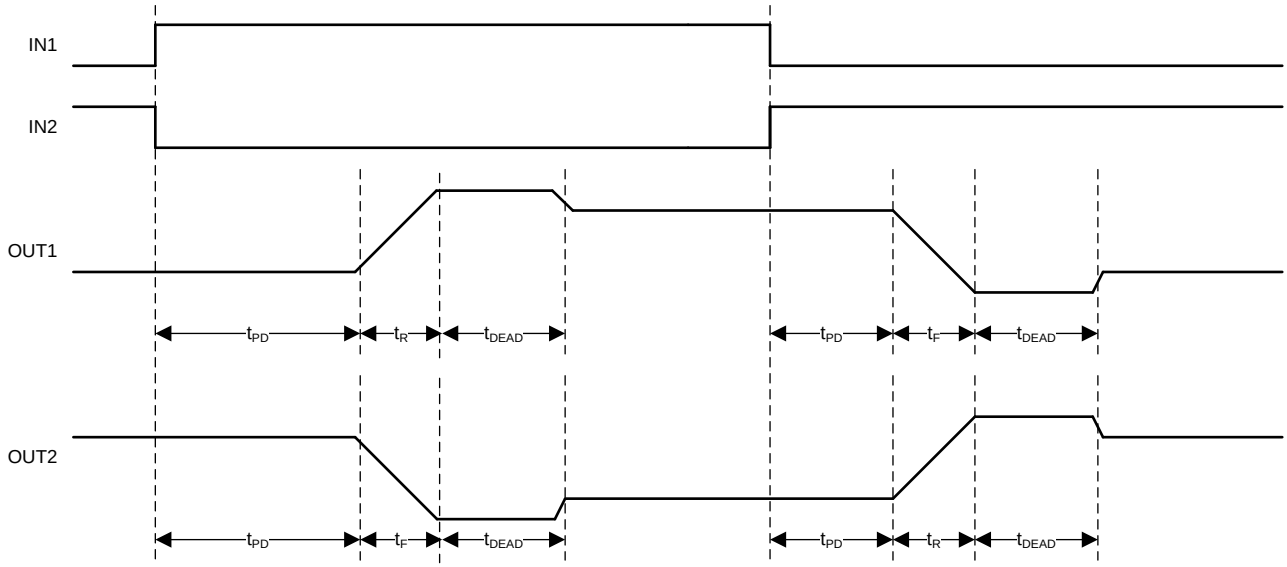


Figure 6. Propagation Delay Time

7.3.5 Protection Circuits

The DRV8872 device is fully protected against VM undervoltage, overcurrent, and overtemperature events. When the device is in a protected state, nFAULT is driven low. When the fault condition is removed, nFAULT becomes a high-impedance state.

7.3.5.1 VM Undervoltage Lockout (UVLO)

If at any time the voltage on the VM pin falls below the undervoltage-lockout threshold voltage, all FETs in the H-bridge are disabled. Operation resumes when VM rises above the UVLO threshold.

7.3.5.2 Overcurrent Protection (OCP)

If the output current exceeds the OCP threshold I_{OCP} for longer than t_{OCP}, all FETs in the H-bridge are disabled for a duration of t_{RETRY}. After that, the H-bridge re-enables according to the state of the INx pins. If the overcurrent fault is still present, the cycle repeats; otherwise normal device operation resumes.

7.3.5.3 Thermal Shutdown (TSD)

If the die temperature exceeds safe limits, all FETs in the H-bridge is disabled. After the die temperature has fallen to a safe level, operation automatically resumes.

Table 2. Protection Functionality

FAULT	CONDITION	H-BRIDGE BECOMES	NFAULT BECOMES	RECOVERY
VM undervoltage lockout (UVLO)	$VM < V_{UVLO}$	Disabled	Low	$VM > V_{UVLO}$
Overcurrent (OCP)	$I_{OUT} > I_{OCP}$	Disabled	Low	t_{RETRY}
Thermal shutdown (TSD)	$T_J > 150°C$	Disabled	Low	$T_J < T_{SD} - T_{HYS}$

7.4 Device Functional Modes

The DRV8872 device can be used in multiple ways to drive a brushed DC motor.

7.4.1 PWM With Current Regulation

This scheme uses all of the capabilities of the device. The I_{TRIP} current is set above the normal operating current, and high enough to achieve an adequate spin-up time, but low enough to constrain current to a desired level. Motor speed is controlled by the duty cycle of one of the inputs, while the other input is static. Brake and slow decay is typically used during the off-time.

7.4.2 PWM Without Current Regulation

If current regulation is not needed, the ISEN pin should be directly connected to the PCB ground plane. This mode provides the highest possible peak current: up to 3.6 A for a few hundred milliseconds (depending on PCB characteristics and the ambient temperature). If current exceeds 3.6 A, the device might reach overcurrent protection (OCP) or over-temperature shutdown (TSD). If that occurs, the device disables and protects itself for about 3 ms (t_{RETRY}) and then resumes normal operation.

7.4.3 Static Inputs With Current Regulation

The IN1 and IN2 pins can be set high and low for 100% duty cycle drive, and ITRIP can be used to control the current, speed, and torque capability of the motor.

7.4.4 VM Control

In some systems, varying VM as a means of changing motor speed is desirable. See the *Motor Voltage* section for more information.

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8 Application and Implementation

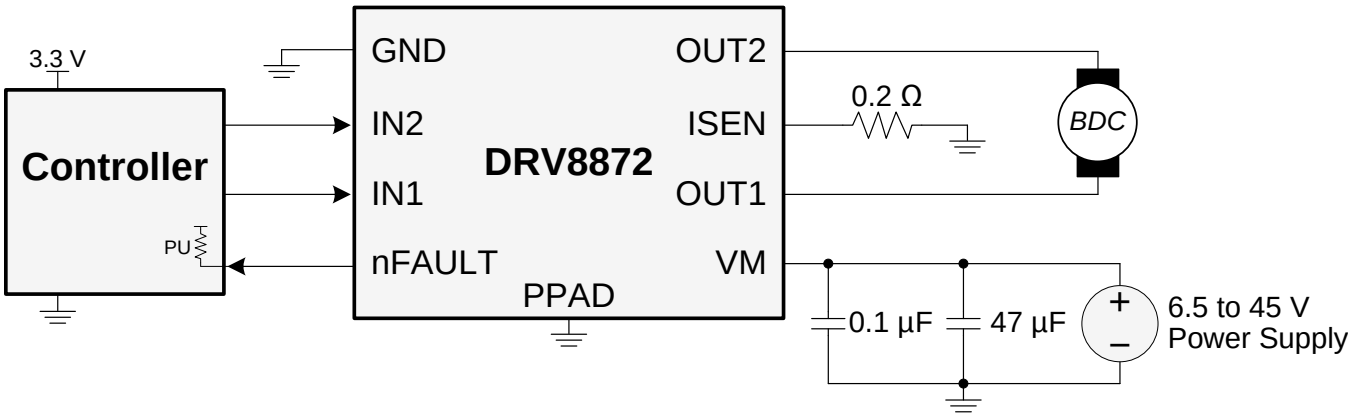
NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The DRV8872 device is typically used to drive one brushed DC motor.

8.2 Typical Application



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Figure 7. Typical Connections

8.2.1 Design Requirements

Table 3 lists the design parameters.

Table 3. Design Parameters

DESIGN PARAMETER	REFERENCE	EXAMPLE VALUE
Motor voltage	V_M	24 V
Motor RMS current	I_{RMS}	0.8 A
Motor startup current	I_{START}	2 A
Motor current trip point	I_{TRIP}	2.2 A
Sense resistance	R_{ISEN}	0.16 Ω
PWM frequency	f_{PWM}	5 kHz

8.2.2 Detailed Design Procedure

8.2.2.1 Motor Voltage

The motor voltage used depends on the ratings of the motor selected and the desired RPM. A higher voltage spins a brushed DC motor faster with the same PWM duty cycle applied to the power FETs. A higher voltage also increases the rate of current change through the inductive motor windings.

8.2.2.2 Drive Current

The current path is through the high-side sourcing DMOS power driver, motor winding, and low-side sinking DMOS power driver. Power dissipation losses in one source and sink DMOS power driver are shown in Equation 2.

$$P_D = I^2 \left(R_{DS(on)Source} + R_{DS(on)Sink} \right) \quad (2)$$

The DRV8872 device has been measured to be capable of 2-A RMS current at 25°C on standard FR-4 PCBs. The maximum RMS current varies based on the PCB design, ambient temperature, and PWM frequency. Typically, switching the inputs at 200 kHz compared to 20 kHz causes 20% more power loss in heat.

8.2.2.3 Sense Resistor

For optimal performance, the sense resistor must have the features that follow:

- Surface-mount device
- Low inductance
- Rated for high enough power
- Placed closely to the motor driver

The power dissipated by the sense resistor equals $I_{RMS}^2 \times R$. For example, if peak motor current is 3 A, RMS motor current is 1.5 A, and a 0.2-Ω sense resistor is used, the resistor dissipates $1.5\ A^2 \times 0.2\ \Omega = 0.45$ W. The power quickly increases with higher current levels.

Resistors typically have a rated power within some ambient temperature range, along with a derated power curve for high ambient temperatures. When a PCB is shared with other components generating heat, the system designer should add margin. It is always best to measure the actual sense resistor temperature in a final system.

Because power resistors are larger and more expensive than standard resistors, multiple standard resistors can be used in parallel, between the sense node and ground. This configuration distributes the current and heat dissipation.

8.2.3 Application Curves

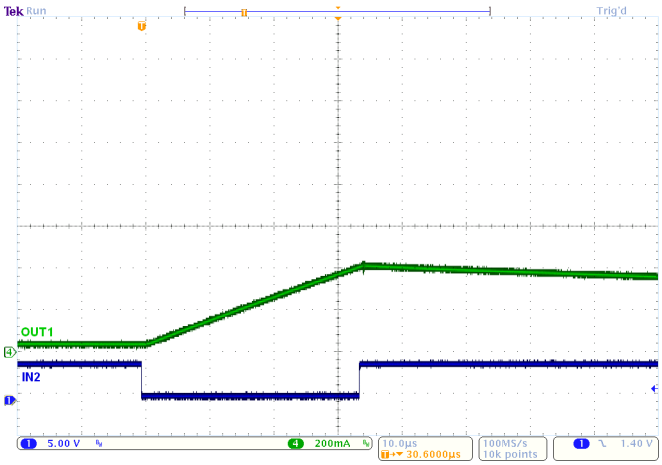


Figure 8. Current Ramp With a 2-Ω, 1 mH, RL Load and VM = 12 V

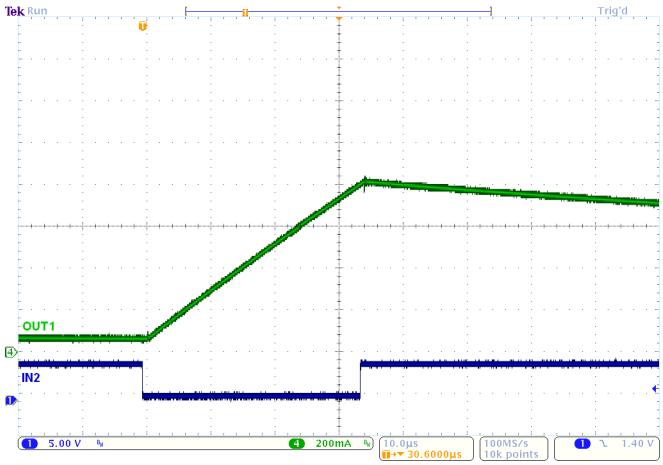


Figure 9. Current Ramp With a 2-Ω, 1 mH, RL Load and VM = 24 V

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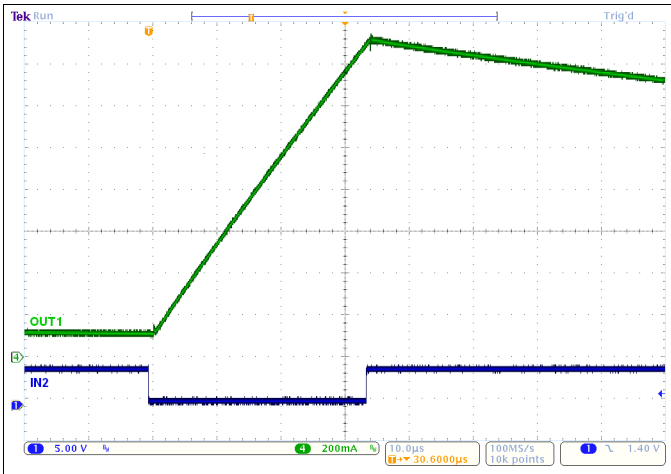


Figure 10. Current Ramp With a 2-Ω, 1 mH, RL Load and VM = 45 V

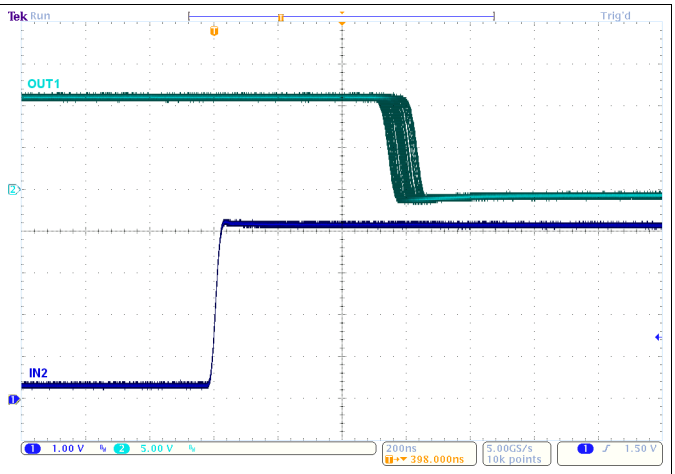


Figure 11. t_{PD}

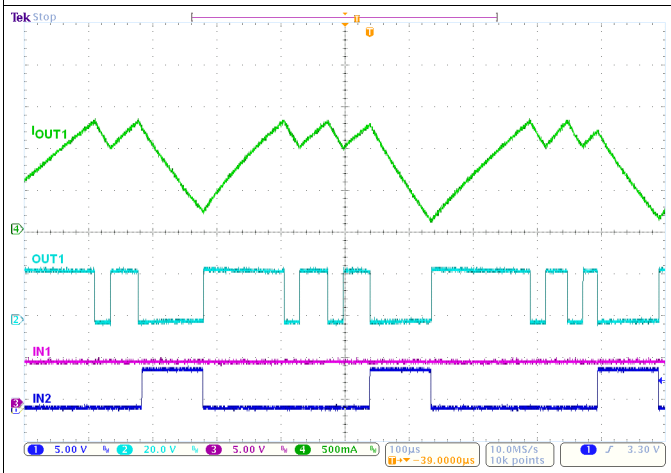


Figure 12. Current Regulation With R_{SENSE} = 0.26 Ω

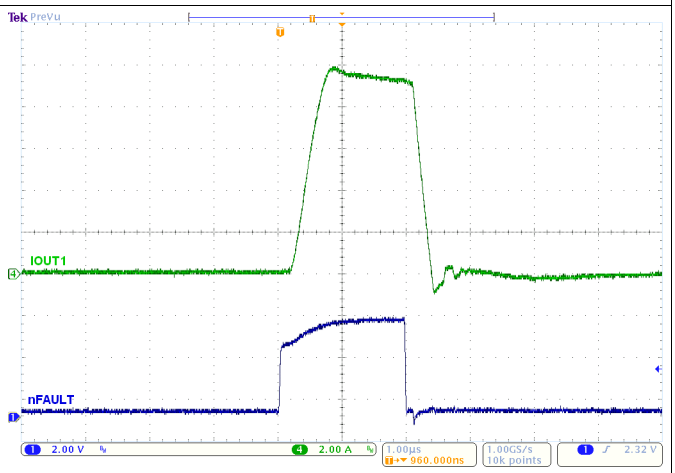


Figure 13. OCP With 24 V and Outputs Shorted Together

9 Power Supply Recommendations

9.1 Bulk Capacitance

Having appropriate local bulk capacitance is an important factor in motor drive system design. More bulk capacitance is generally beneficial but with the disadvantages of increased cost and physical size.

The amount of local capacitance needed depends on a variety of factors, including:

- The highest current required by the motor system
- The power supply's capacitance and ability to source current
- The amount of parasitic inductance between the power supply and motor system
- The acceptable voltage ripple
- The type of motor used (brushed DC, brushless DC, stepper)
- The motor braking method

The inductance between the power supply and motor drive system limits the rate that the current can change from the power supply. If the local bulk capacitance is too small, the system responds to excessive current demands or dumps from the motor with a change in voltage. When adequate bulk capacitance is used, the motor voltage remains stable and high current can be quickly supplied.

The data sheet generally provides a recommended value, but system-level testing is required to determine the appropriate sized bulk capacitor.

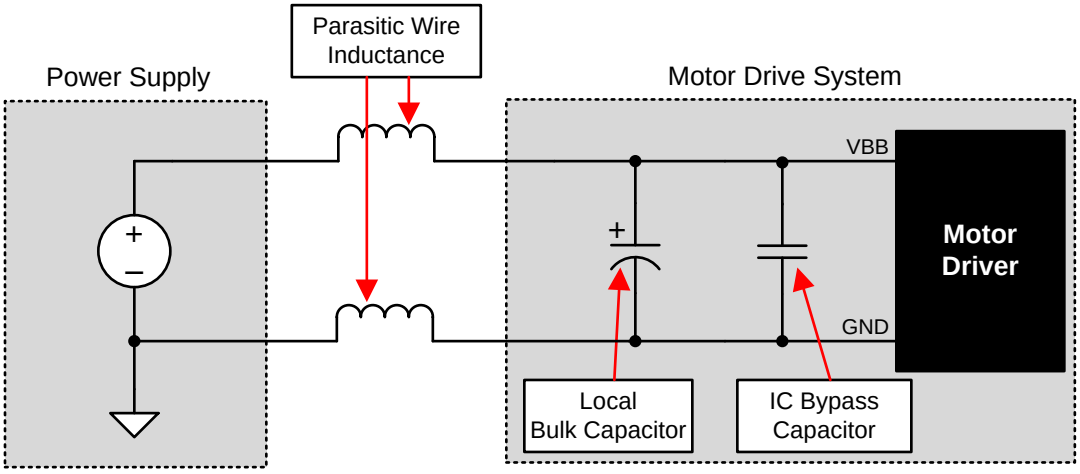


Figure 14. Example Setup of Motor Drive System With External Power Supply

The voltage rating for bulk capacitors should be higher than the operating voltage, to provide margin for cases when the motor transfers energy to the supply.

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10 Layout

10.1 Layout Guidelines

The bulk capacitor should be placed to minimize the distance of the high-current path through the motor driver device. The connecting metal trace widths should be as wide as possible, and numerous vias should be used when connecting PCB layers. These practices minimize inductance and allow the bulk capacitor to deliver high current.

Small-value capacitors should be ceramic, and placed closely to device pins.

The high-current device outputs should use wide metal traces.

The device thermal pad should be soldered to the PCB top-layer ground plane. Multiple vias should be used to connect to a large bottom-layer ground plane. The use of large metal planes and multiple vias help dissipate the $I^2 \times R_{DS(on)}$ heat that is generated in the device.

Figure 15 shows the recommended layout and component placement.

10.2 Layout Example

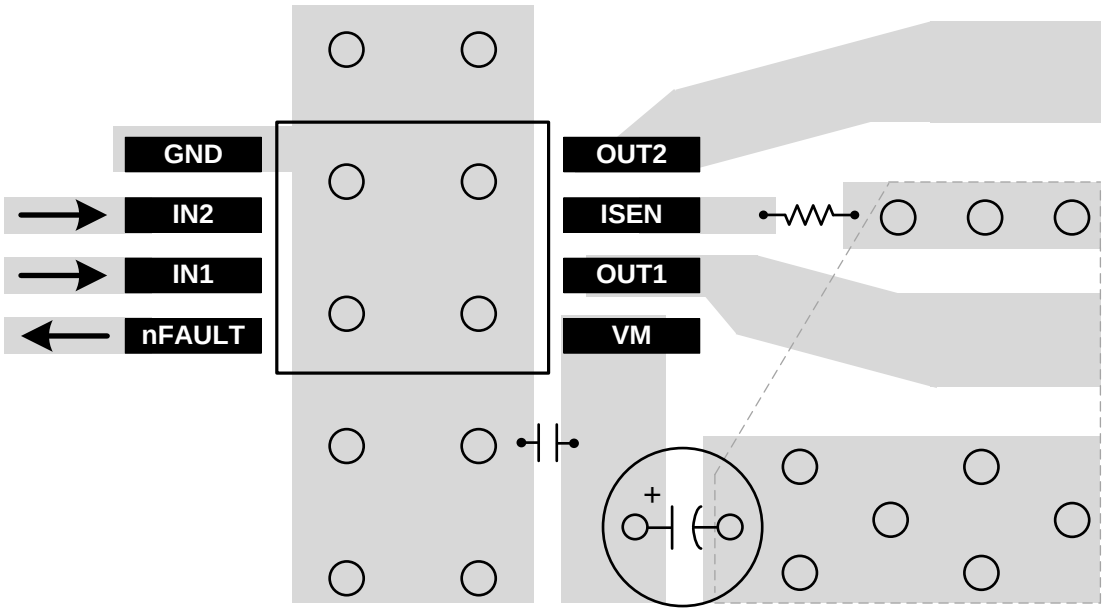


Figure 15. Layout Recommendation

10.3 Thermal Considerations

The DRV8872 device has thermal shutdown (TSD) as described in the *Thermal Shutdown (TSD)* section. If the die temperature exceeds approximately 175°C, the device is disabled until the temperature drops below the temperature hysteresis level.

Any tendency of the device to enter TSD is an indication of either excessive power dissipation, insufficient heatsinking, or too high of an ambient temperature.

10.4 Power Dissipation

Power dissipation in the DRV8872 device is dominated by the power dissipated in the output FET resistance, $R_{DS(on)}$. Use Equation 2 from the *Drive Current* section to calculate the estimated average power dissipation of when driving a load.

Note that at startup, the output current is much higher than normal running current; this peak current and its duration must be also be considered.

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Power Dissipation (continued)

The maximum amount of power that can be dissipated in the device is dependent on ambient temperature and heatsinking.

NOTE

$R_{DS(on)}$ increases with temperature, so as the device heats, the power dissipation increases. This fact must be taken into consideration when sizing the heatsink.

The power dissipation of the DRV8872 is a function of RMS motor current and the FET resistance ($R_{DS(ON)}$) of each output.

$$\text{Power} \approx I_{RMS}^2 \times \left(\text{High-side } R_{DS(ON)} + \text{ Low-side } R_{DS(ON)}\right) \quad (3)$$

For this example, the ambient temperature is 58°C, and the junction temperature reaches 80°C. At 58°C, the sum of $R_{DS(ON)}$ is about 0.72 Ω. With an example motor current of 0.8 A, the dissipated power in the form of heat is 0.8 A^2 × 0.72 Ω = 0.46 W.

The temperature that the DRV8872 reaches depends on the thermal resistance to the air and PCB. Soldering the device PowerPAD to the PCB ground plane, with vias to the top and bottom board layers, is important to dissipate heat into the PCB and reduce the device temperature. In the example used here, the DRV8872 had an effective thermal resistance $R_{\theta JA}$ of 48°C/W, and a T_J value as shown in Equation 4.

$$T_J = T_A + (P_D \times R_{\theta JA}) = 58°C + (0.46\ W \times 48°C/W) = 80°C \quad (4)$$

10.4.1 Heatsinking

The PowerPAD package uses an exposed pad to remove heat from the device. For proper operation, this pad must be thermally connected to copper on the PCB to dissipate heat. On a multi-layer PCB with a ground plane, this connection can be accomplished by adding a number of vias to connect the thermal pad to the ground plane.

On PCBs without internal planes, a copper area can be added on either side of the PCB to dissipate heat. If the copper area is on the opposite side of the PCB from the device, thermal vias are used to transfer the heat between top and bottom layers.

For details about how to design the PCB, refer to the TI application report, *PowerPAD™ Thermally Enhanced Package*, and the TI application brief, *PowerPAD Made Easy™*, available at www.ti.com. In general, the more copper area that can be provided, the more power can be dissipated.

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11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation, see the following:

- *PowerPAD™ Thermally Enhanced Package*
- *PowerPAD™ Made Easy*
- *Current Recirculation and Decay Modes*
- *Calculating Motor Driver Power Dissipation*
- *DRV8872 Evaluation Module*
- *Understanding Motor Driver Current Ratings*

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DRV8872DDAR	Active	Production	SO PowerPAD (DDA) | 8	2500 | LARGE T&R	Yes	NIPDAU | NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	8872
DRV8872DDAR.A	Active	Production	SO PowerPAD (DDA) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	8872
DRV8872DDAR.B	Active	Production	SO PowerPAD (DDA) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	8872

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF DRV8872 :

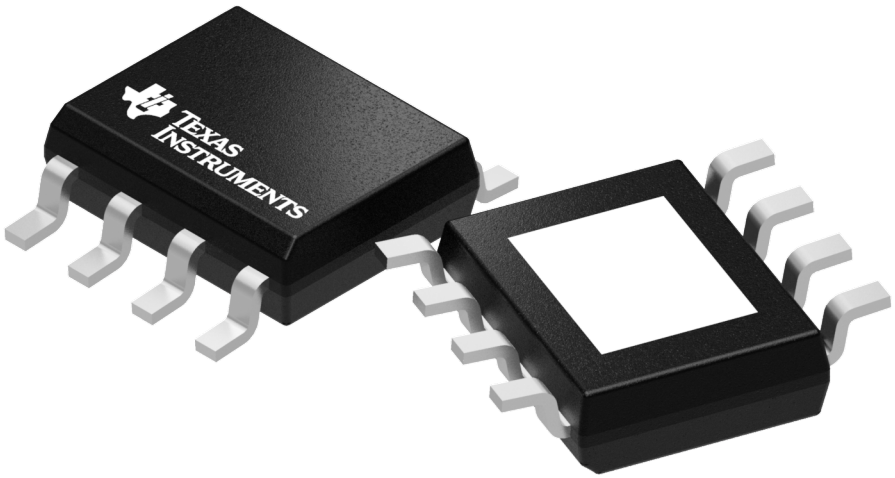
- Automotive : DRV8872-Q1

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

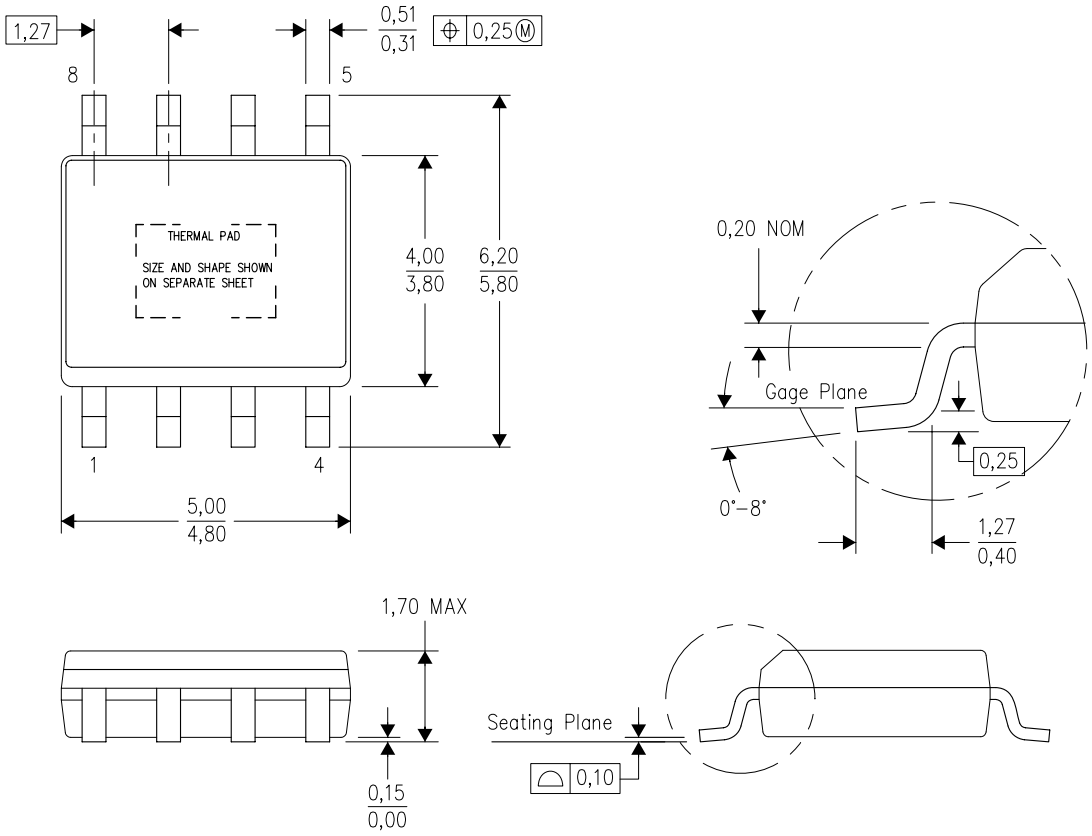
DDA 8 PowerPAD™ SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

DDA (R–PDSO–G8) PowerPAD™ PLASTIC SMALL–OUTLINE



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5–1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. This package complies to JEDEC MS–012 variation BA

PowerPAD is a trademark of Texas Instruments.

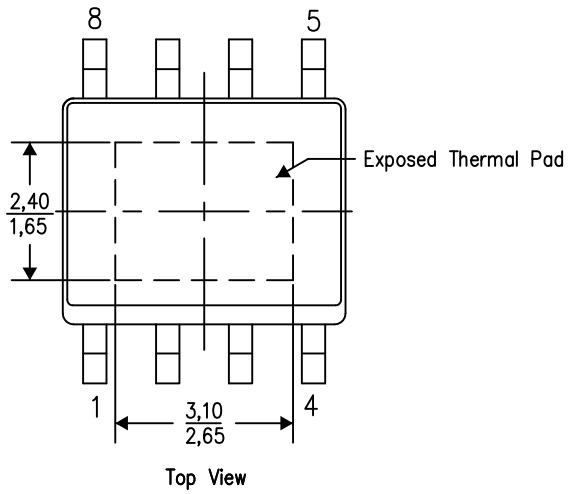
DDA (R–PDSO–G8) PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



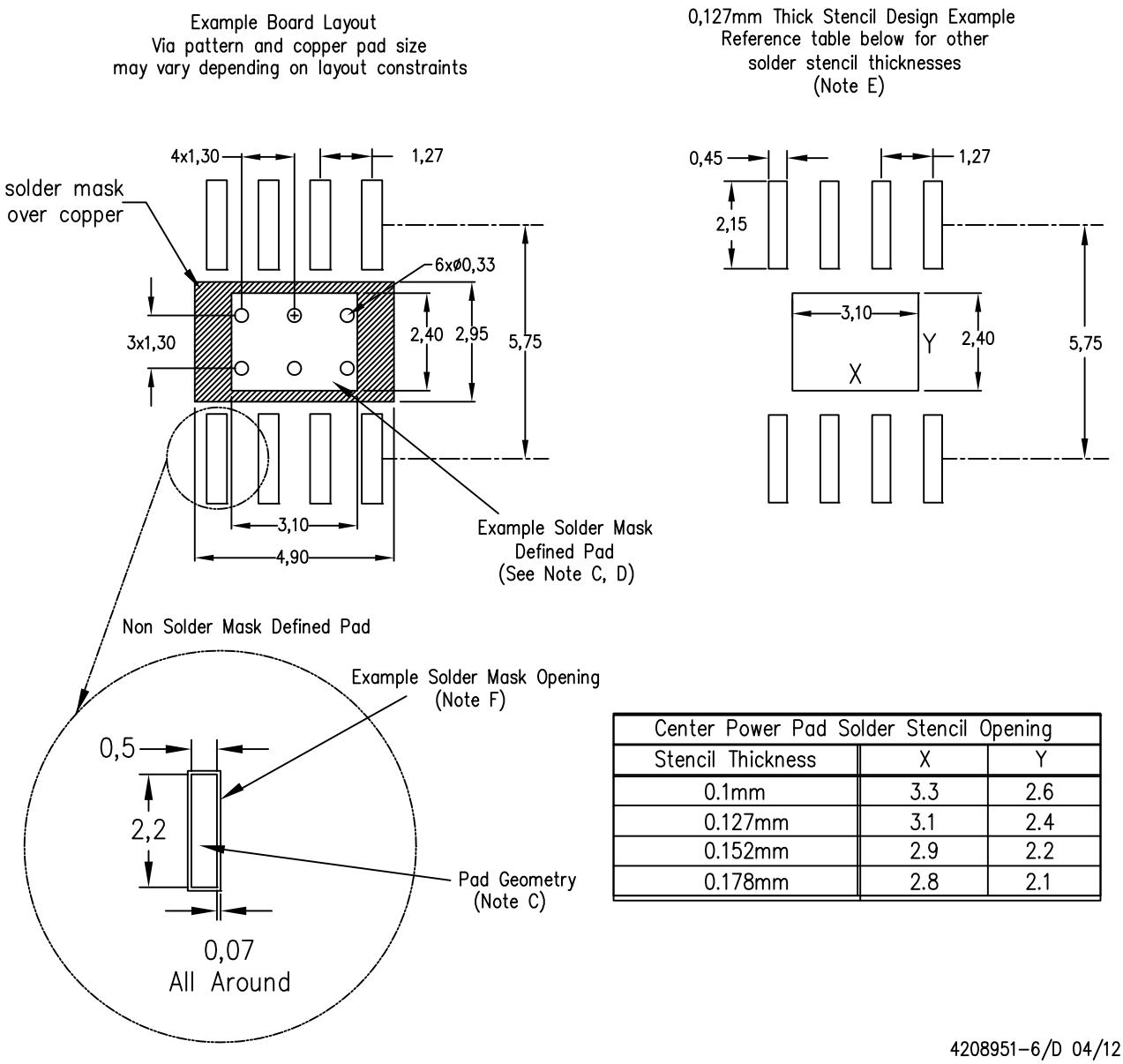
Exposed Thermal Pad Dimensions

4206322–6/L 05/12

NOTE: A. All linear dimensions are in millimeters

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DDA (R–PDSO–G8) PowerPAD™ PLASTIC SMALL OUTLINE



Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	3.3	2.6
0.127mm	3.1	2.4
0.152mm	2.9	2.2
0.178mm	2.8	2.1

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.
F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

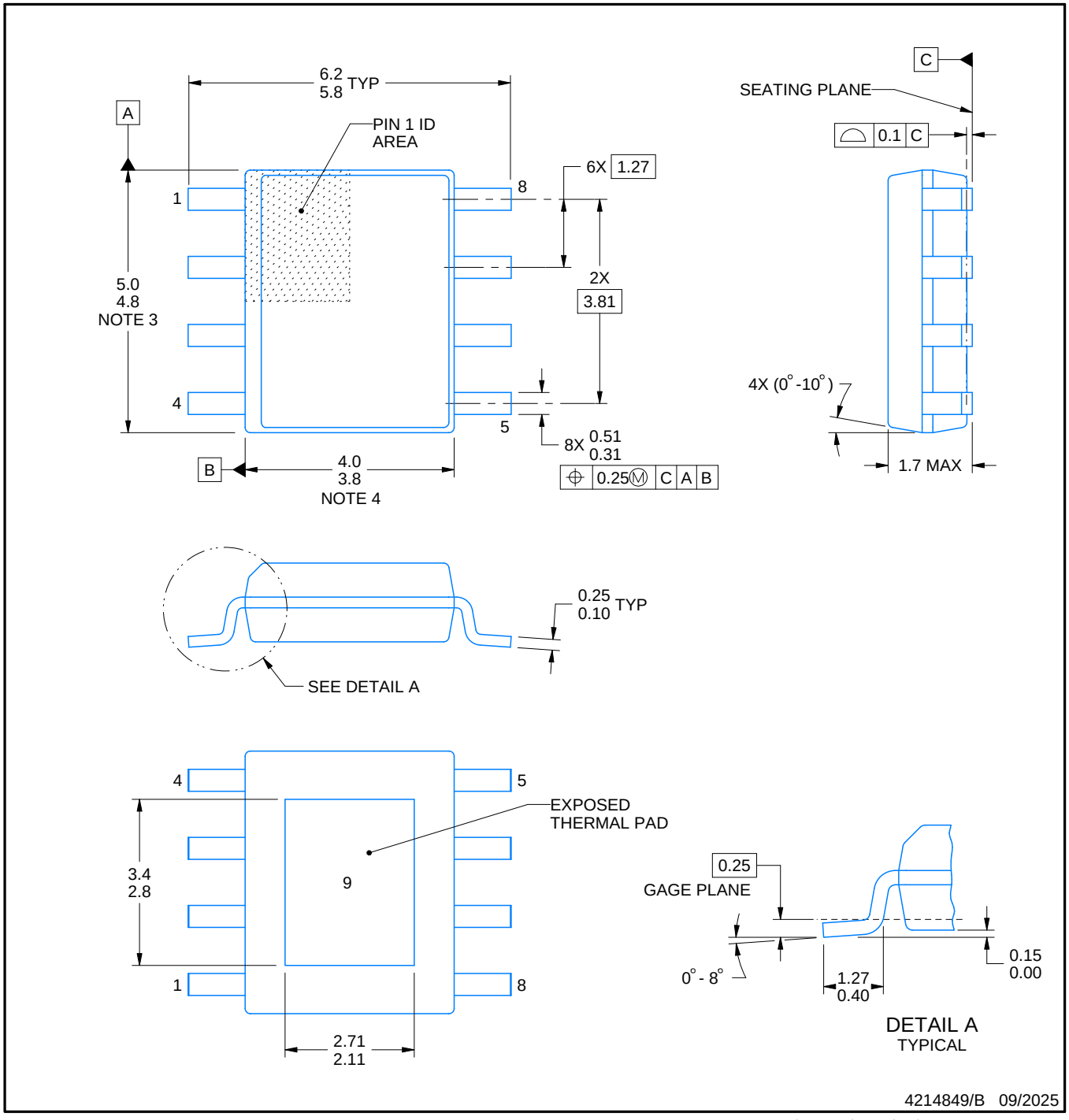
PowerPAD is a trademark of Texas Instruments.

PACKAGE OUTLINE

DDA0008B

PowerPAD™ SOIC - 1.7 mm max height

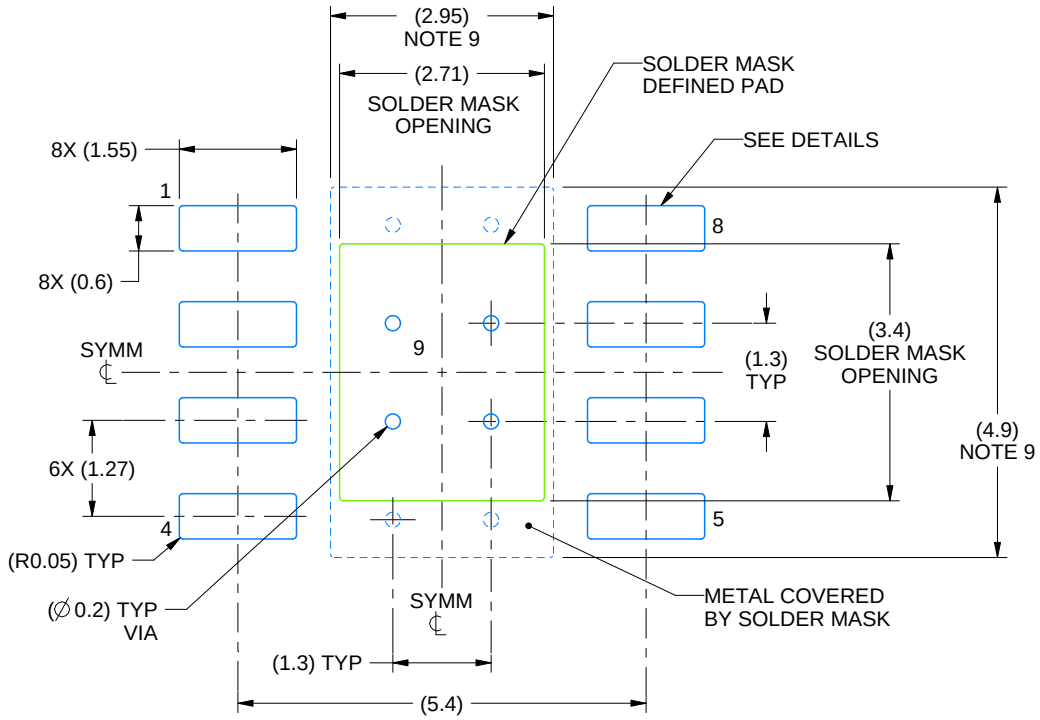
PLASTIC SMALL OUTLINE



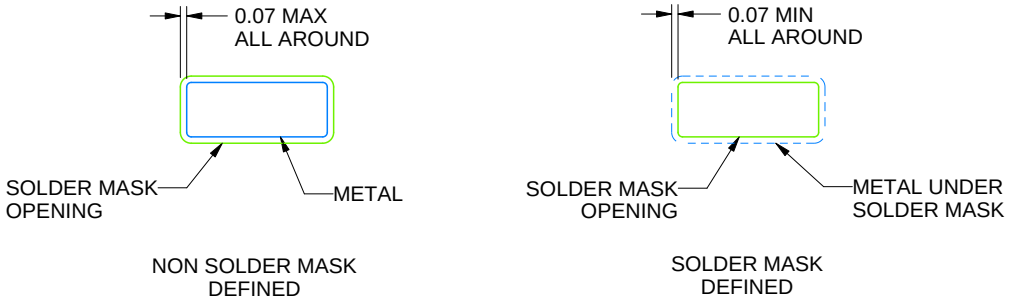
PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MS-012.



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
PADS 1-8

4214849/B 09/2025

NOTES: (continued)

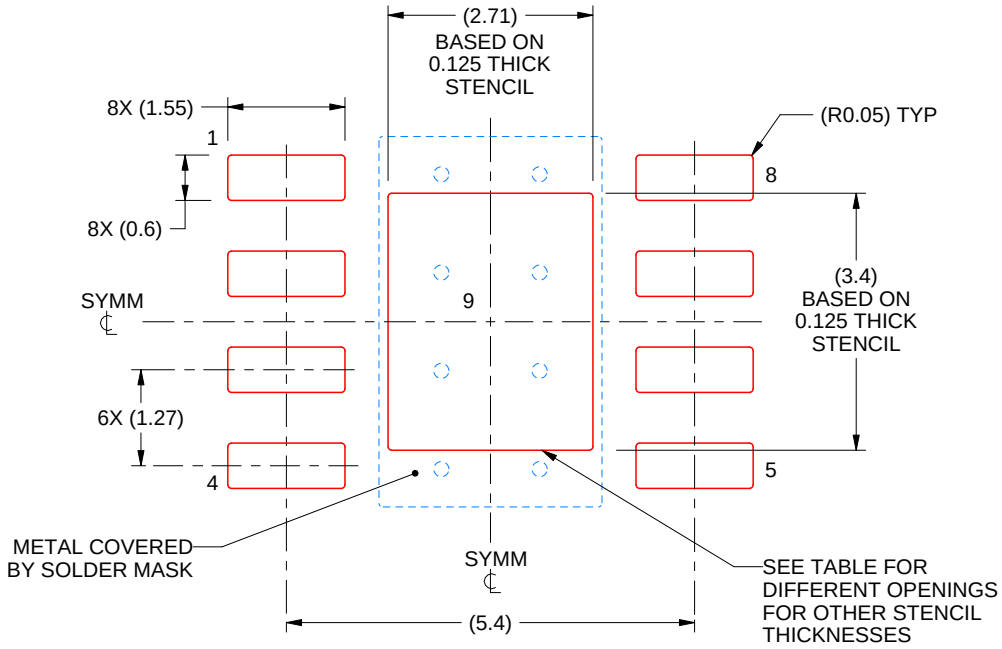
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.
10. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DDA0008B

PowerPAD™ SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
EXPOSED PAD
100% PRINTED SOLDER COVERAGE BY AREA
SCALE:10X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	3.03 X 3.80
0.125	2.71 X 3.40 (SHOWN)
0.150	2.47 X 3.10
0.175	2.29 X 2.87

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NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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Last updated 10/2025